

Dephasing in Disordered Conductors due to Fluctuating Electric Fields

Axel Völker and Peter Kopietz

*Institut für Theoretische Physik der Universität Göttingen, Bunsenstrasse 9, D-37073 Göttingen,
Germany*

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Abstract

We develop a novel eikonal expansion for the Cooperon to study the effect of space- and time-dependent electric fields on the dephasing rate of disordered conductors. For randomly fluctuating fields with arbitrary covariance we derive a general expression for the dephasing rate which is free of infrared divergencies in reduced dimensions. For time-dependent external fields with finite wavelength and sufficiently small amplitude we show that the dephasing rate is proportional to the square root of the electromagnetic power coupled into the system, in agreement with data by Wang and Lindelof [Phys. Rev. Lett. **59**, 1156 (1987)].

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I. INTRODUCTION

The dephasing time τ_ϕ of a particle in a quantum system is the time over which its wavefunction maintains phase coherence. For diffusive systems in dimensions $d = 1$ and $d = 2$ the dephasing time can be obtained experimentally from the weak-localization correction to the conductivity in a magnetic field. Recently Mohanty, Jariwala and Webb [1] used this method to measure τ_ϕ as a function of the temperature T in gold wires. They found that at sufficiently low temperatures τ_ϕ approaches a finite value. This is in disagreement with the generally accepted point of view [2] that in thermal equilibrium τ_ϕ should diverge as T^{-p} , $p > 0$, for $T \rightarrow 0$. A proposal that the observed saturation of τ_ϕ is an intrinsic ground-state property of interacting electrons in a random potential [3] has been heavily criticized [4]. Until now, there is no general agreement on the microscopic mechanism for the observed saturation of τ_ϕ at low temperatures.

One possible reason for this saturation might be external microwave radiation that is unintentionally coupled into the system [5]. According to Ref. [6] the dephasing rate $1/\tau_{AC}$ due to a time-dependent but spatially constant electric field is proportional to the microwave power P absorbed by the system for small P , and crosses over to a $P^{1/5}$ -law for larger P . Experimentally the effect of microwaves on weak localization has been studied by several authors [7–10]. Most of the data by Wang and Lindelof [7] can be fitted with $1/\tau_{AC} \propto P^{1/2}$. Below we shall offer a simple explanation for this behavior. More recent data by Webb *et al.* [10] are consistent with a $P^{1/5}$ -law at high powers P , but in this experiment the microwaves seem to heat the sample, an effect which has not been taken into account in Ref. [6], and which we will neglect as well.

Following Altshuler *et al.* [6,11], we define the dephasing rate in the diffusive regime via the weak localization correction $\delta\sigma$ to the static conductivity. In the presence of an external electric field $\delta\sigma$ can be written as [6,11,12]

$$\delta\sigma = -\frac{\sigma_0}{\pi\nu_d} \int_{\tau_{el}}^{\infty} dt \lim_{T_0 \rightarrow \infty} \frac{1}{2T_0} \int_{-T_0}^{T_0} dt_0 \mathcal{C}(\mathbf{r}, \mathbf{r}, \frac{t}{2}, -\frac{t}{2}, t_0), \quad (1)$$

where σ_0 is the Drude conductivity, ν_d is the d -dimensional density of states, and τ_{el} is the momentum relaxation time. The Cooperon $\mathcal{C}$ satisfies [12–14]

$$\begin{aligned} & \left[\partial_t + D\hat{\mathbf{P}}_{\mathbf{r}}^2 + \Gamma_0 + i[V(\mathbf{r}, t_0 + t) - V(\mathbf{r}, t_0 - t)] \right] \\ & \times \mathcal{C}(\mathbf{r}, \mathbf{r}', t, t', t_0) = \delta(\mathbf{r} - \mathbf{r}')\delta(t - t') , \end{aligned} \quad (2)$$

where $\hat{\mathbf{P}}_{\mathbf{r}} = -i\nabla_{\mathbf{r}}$ is the momentum operator, D is the diffusion coefficient, and the phenomenological cutoff Γ_0 describes dephasing due to processes that are not explicitly treated in our calculation, such as inelastic electron-phonon scattering or electron-electron scattering with energy-transfers $|\omega| \gtrsim T$. The potential $V(\mathbf{r}, t)$ is related to the longitudinal electric field via $e\mathbf{E}(\mathbf{r}, t) = \nabla_{\mathbf{r}}V(\mathbf{r}, t)$, where $-e$ is the charge of the electron. For $\Gamma_0 = V = 0$ the t -integration in Eq.(1) diverges in $d \leq 2$ at the upper limit, but for finite Γ_0 or V the integration is cut off at some finite time, the so-called dephasing time.

II. EIKONAL EXPANSION

Formally Eq.(2) looks like the differential equation for the imaginary-time single-particle Green's function of an electron in a fluctuating external potential

$$V_{t_0}(\mathbf{r}, t) = i[V(\mathbf{r}, t_0 + t) - V(\mathbf{r}, t_0 - t)]. \quad (3)$$

The real time version of this problem has been discussed extensively in the quantum field theory literature [15]. By means of a simple modification of the method developed by E. S. Fradkin [15] (see also Ref. [16]) we obtain the solution of Eq.(2) in the following form [12]

$$\begin{aligned} \mathcal{C}(\mathbf{r}, \mathbf{r}', t, t', t_0) &= \Theta(t - t') \int \frac{d\mathbf{k}}{(2\pi)^d} e^{i\mathbf{k} \cdot (\mathbf{r} - \mathbf{r}')} \\ &\times e^{-(\Gamma_0 + D\mathbf{k}^2)(t - t') - F(\mathbf{k}, t - t'; \mathbf{r}, t)} , \end{aligned} \quad (4)$$

where the function F satisfies the eikonal equation

$$\begin{aligned} & \left[\partial_\tau + \partial_t + D(\hat{\mathbf{P}}_{\mathbf{r}}^2 + 2\mathbf{k} \cdot \hat{\mathbf{P}}_{\mathbf{r}}) \right] F(\mathbf{k}, \tau; \mathbf{r}, t) = \\ & V_{t_0}(\mathbf{r}, t) + D \left[\hat{\mathbf{P}}_{\mathbf{r}} F(\mathbf{k}, \tau; \mathbf{r}, t) \right]^2 , \end{aligned} \quad (5)$$

with boundary condition $F(\mathbf{k}, 0; \mathbf{r}, t) = 0$. Although in general Eq.(5) cannot be solved exactly, we can easily obtain an expansion of F in powers of the potential $V_{t_0}(\mathbf{r}, t)$. Setting

$$F(\mathbf{k}, \tau; \mathbf{r}, t) = \sum_{n=1}^{\infty} F_n(\mathbf{k}, \tau; \mathbf{r}, t), \quad (6)$$

where F_n involves by definition n powers of V_{t_0} , successive terms may be calculated recursively [12,15,16]. For our purpose we need only the first two terms. The linear term is

$$F_1(\mathbf{k}, \tau; \mathbf{r}, t) = \int \frac{d\mathbf{q}d\omega}{(2\pi)^{d+1}} e^{i(\mathbf{q}\cdot\mathbf{r}-\omega t)} V_{t_0}(\mathbf{q}, \omega) \times \frac{1 - e^{-[D(\mathbf{q}^2+2\mathbf{k}\cdot\mathbf{q})-i\omega]\tau}}{D(\mathbf{q}^2+2\mathbf{k}\cdot\mathbf{q})-i\omega}. \quad (7)$$

Here

$$V_{t_0}(\mathbf{q}, \omega) = i[e^{-i\omega t_0}V(\mathbf{q}, \omega) - e^{i\omega t_0}V(\mathbf{q}, -\omega)] \quad (8)$$

is the Fourier transform of $V_{t_0}(\mathbf{r}, t)$, where

$$V(\mathbf{q}, \omega) = \int d\mathbf{r} \int dt e^{-i(\mathbf{q}\cdot\mathbf{r}-\omega t)} V(\mathbf{r}, t). \quad (9)$$

From Eq.(5) we find that the quadratic term is related to the linear one via

$$F_2(\mathbf{k}, \tau; \mathbf{r}, t) = - \int_0^\tau d\tau' e^{(D\hat{\mathbf{P}}_{\mathbf{r}}^2+2D\mathbf{k}\cdot\hat{\mathbf{P}}_{\mathbf{r}}+\partial_t)(\tau'-\tau)} D [\hat{\mathbf{P}}_{\mathbf{r}} F_1(\mathbf{k}, \tau'; \mathbf{r}, t)]^2. \quad (10)$$

The explicit calculation yields

$$F_2(\mathbf{k}, \tau; \mathbf{r}, t) = \int \frac{d\mathbf{q}_1 d\omega_1}{(2\pi)^{d+1}} \int \frac{d\mathbf{q}_2 d\omega_2}{(2\pi)^{d+1}} \times e^{i[(\mathbf{q}_1+\mathbf{q}_2)\cdot\mathbf{r}-(\omega_1+\omega_2)t]} V_{t_0}(\mathbf{q}_1, \omega_1) V_{t_0}(\mathbf{q}_2, \omega_2) \times \frac{(D\mathbf{q}_1 \cdot \mathbf{q}_2) e^{-[D((\mathbf{q}_1+\mathbf{q}_2)^2+2\mathbf{k}\cdot(\mathbf{q}_1+\mathbf{q}_2))-i(\omega_1+\omega_2)]\tau}}{[D(\mathbf{q}_1^2+2\mathbf{k}\cdot\mathbf{q}_1)-i\omega_1][D(\mathbf{q}_2^2+2\mathbf{k}\cdot\mathbf{q}_2)-i\omega_2]} \times \left\{ \frac{e^{[D((\mathbf{q}_1+\mathbf{q}_2)^2+2\mathbf{k}\cdot(\mathbf{q}_1+\mathbf{q}_2))-i(\omega_1+\omega_2)]\tau} - 1}{D((\mathbf{q}_1+\mathbf{q}_2)^2+2\mathbf{k}\cdot(\mathbf{q}_1+\mathbf{q}_2))-i(\omega_1+\omega_2)} + \frac{e^{2D\mathbf{q}_1\cdot\mathbf{q}_2\tau} - 1}{2D\mathbf{q}_1\cdot\mathbf{q}_2} - \frac{e^{[D(\mathbf{q}_1^2+2\mathbf{k}\cdot\mathbf{q}_1+2\mathbf{q}_1\cdot\mathbf{q}_2)-i\omega_1]\tau} - 1}{D(\mathbf{q}_1^2+2\mathbf{k}\cdot\mathbf{q}_1+2\mathbf{q}_1\cdot\mathbf{q}_2)-i\omega_1} - \frac{e^{[D(\mathbf{q}_2^2+2\mathbf{k}\cdot\mathbf{q}_2+2\mathbf{q}_2\cdot\mathbf{q}_1)-i\omega_2]\tau} - 1}{D(\mathbf{q}_2^2+2\mathbf{k}\cdot\mathbf{q}_2+2\mathbf{q}_2\cdot\mathbf{q}_1)-i\omega_2} \right\}. \quad (11)$$

Because we have made the diffusion approximation, the momentum-integrations in Eqs.(7,11) are restricted to $|\mathbf{q}|, |\mathbf{q}_1|, |\mathbf{q}_2| < 1/\ell \equiv 1/(v_F\tau_{\text{el}})$, and the frequency-integrals to $|\omega|, |\omega_1|, |\omega_2| < 1/\tau_{\text{el}}$. Here ℓ is the elastic mean free path and v_F is the Fermi velocity. For brevity we have not explicitly written out these cutoffs in the above expressions.

III. DEPHASING DUE TO RANDOM FIELDS

A. General case

We now assume that the potential $V(\mathbf{r}, t)$ is a random function with zero average and general covariance

$$\langle V(\mathbf{q}, \omega) V(\mathbf{q}', \omega') \rangle = (2\pi)^{d+1} \delta(\mathbf{q} + \mathbf{q}') \delta(\omega + \omega') g(\mathbf{q}, \omega) , \quad (12)$$

where $\langle \dots \rangle$ denotes averaging over the probability distribution of V . The dephasing rate is then defined in terms of the average $\langle \delta\sigma \rangle$ of Eq.(1). Using the fact that after the averaging the Cooperon is independent of the time t_0 , we obtain from Eqs.(1,4)

$$\langle \delta\sigma \rangle = -\frac{\sigma_0}{\pi\nu_d} \int_{\tau_{\text{el}}}^{\infty} dt \int \frac{d\mathbf{k}}{(2\pi)^d} e^{-(\Gamma_0 + D\mathbf{k}^2)t - \Gamma(\mathbf{k}, t)} , \quad (13)$$

where

$$\Gamma(\mathbf{k}, t) = -\ln \langle e^{-F(\mathbf{k}, t; \mathbf{r}, t/2)} \rangle . \quad (14)$$

We now perform a linked cluster expansion of $\Gamma(\mathbf{k}, t)$ in powers of the correlator $g(\mathbf{q}, \omega)$. To first order we find

$$\Gamma(\mathbf{k}, t) \approx \Gamma_1(\mathbf{k}, t) + \Gamma_2(\mathbf{k}, t) , \quad (15)$$

where

$$\Gamma_1(\mathbf{k}, t) = -\frac{1}{2} \langle F_1^2(\mathbf{k}, t; \mathbf{r}, t/2) \rangle , \quad (16)$$

$$\Gamma_2(\mathbf{k}, t) = \langle F_2(\mathbf{k}, t; \mathbf{r}, t/2) \rangle . \quad (17)$$

Introducing the notation $E_{\mathbf{k}}(\mathbf{q}) = D(\mathbf{q}^2 + 2\mathbf{k} \cdot \mathbf{q})$ we obtain

$$\begin{aligned} \Gamma_1(\mathbf{k}, t) = & \int \frac{d\mathbf{q}d\omega}{(2\pi)^{d+1}} g(\mathbf{q}, \omega) \\ & \times \left\{ \frac{1 - e^{-(E_{\mathbf{k}}(\mathbf{q}) - i\omega)t}}{E_{\mathbf{k}}(\mathbf{q}) - i\omega} \frac{1 - e^{-(E_{\mathbf{k}}(-\mathbf{q}) + i\omega)t}}{E_{\mathbf{k}}(-\mathbf{q}) + i\omega} \right. \\ & \left. - e^{-i\omega t} \frac{1 - e^{-(E_{\mathbf{k}}(\mathbf{q}) - i\omega)t}}{E_{\mathbf{k}}(\mathbf{q}) - i\omega} \frac{1 - e^{-(E_{\mathbf{k}}(-\mathbf{q}) - i\omega)t}}{E_{\mathbf{k}}(-\mathbf{q}) - i\omega} \right\}, \end{aligned} \quad (18)$$

$$\begin{aligned} \Gamma_2(\mathbf{k}, t) = & \int \frac{d\mathbf{q}d\omega}{(2\pi)^{d+1}} g(\mathbf{q}, \omega) \frac{2D\mathbf{q}^2}{E_{\mathbf{k}}(\mathbf{q}) - i\omega} \\ & \times \left\{ \frac{1}{E_{\mathbf{k}}(-\mathbf{q}) + i\omega} \left[t + \frac{1 - e^{-2D\mathbf{q}^2 t}}{2D\mathbf{q}^2} - \frac{1 - e^{-(E_{\mathbf{k}}(\mathbf{q}) - i\omega)t}}{E_{\mathbf{k}}(\mathbf{q}) - i\omega} - \frac{1 - e^{-(E_{\mathbf{k}}(-\mathbf{q}) + i\omega)t}}{E_{\mathbf{k}}(-\mathbf{q}) + i\omega} \right] \right. \\ & \left. - \frac{1}{E_{\mathbf{k}}(-\mathbf{q}) - i\omega} \left[\frac{\sin(\omega t)}{\omega} + e^{i\omega t} \left[\frac{1 - e^{-2D\mathbf{q}^2 t}}{2D\mathbf{q}^2} - \frac{1 - e^{-(E_{\mathbf{k}}(\mathbf{q}) + i\omega)t}}{E_{\mathbf{k}}(\mathbf{q}) + i\omega} - \frac{1 - e^{-(E_{\mathbf{k}}(-\mathbf{q}) + i\omega)t}}{E_{\mathbf{k}}(-\mathbf{q}) + i\omega} \right] \right] \right\}. \end{aligned} \quad (19)$$

B. Nyquist noise

As a special case let us assume that the potential V is generated by equilibrium fluctuations of the electric field due to the thermal motion of the electrons (Nyquist noise). Then $g(\mathbf{q}, \omega)$ is determined by the fluctuation-dissipation theorem, which implies [11]

$$g(\mathbf{q}, \omega) = -f_{\mathbf{q}} \coth\left(\frac{\omega}{2T}\right) \text{Im}\epsilon^{-1}(\mathbf{q}, \omega), \quad (20)$$

where $f_{\mathbf{q}}$ is the Fourier transform of the bare Coulomb interaction, and the dielectric function of the system is in the diffusive regime given by

$$\epsilon(\mathbf{q}, \omega) = 1 + f_{\mathbf{q}} \nu_d \frac{D\mathbf{q}^2}{D\mathbf{q}^2 - i\omega}. \quad (21)$$

The corresponding dephasing rate in $d = 1, 2, 3$ was calculated by Altshuler *et al.* [11] with the help of a Feynman path-integral representation of the solution of Eq.(2). It is instructive to reproduce the results of Ref. [11] within our eikonal expansion, treating d as a continuous parameter. It is important to note that in the derivation of Eq.(2) the electromagnetic field is treated classically [11,14], so that our calculation takes only into account low-frequency

Fourier components of the screened Coulomb interaction, with $|\omega| \lesssim T$. The correlator $g(\mathbf{q}, \omega)$ in Eqs.(18,19) can then be approximated by

$$g(\mathbf{q}, \omega) \approx \Theta(T - |\omega|) \frac{2T}{\nu_d D \mathbf{q}^2}, \quad (22)$$

Because the momentum integrals in the following analysis will be infrared *and* ultraviolet convergent, no further cutoffs are needed in our approach.

The dephasing rate is determined by the long-time behavior of $\Gamma(t) \equiv \Gamma(\mathbf{k} = 0, t)$. In $d < 2$ we find for $t \gg 1/T$

$$\Gamma(t) \sim C_d \frac{T t^{2-\frac{d}{2}}}{\nu_d D^{\frac{d}{2}}}, \quad (23)$$

where the numerical constant C_d is given by

$$C_d = \frac{2^{3-d}}{\pi^{\frac{d}{2}}(2-d)(4-d)}. \quad (24)$$

Because $\Gamma(t)$ grows for large t faster than linear, the term $\Gamma_0 t$ in Eq.(13) is negligible, and the dephasing rate may be defined by $\Gamma(\tau_\phi) = 1$, which yields

$$\frac{1}{\tau_\phi} = \left[\frac{C_d T}{\nu_d D^{d/2}} \right]^{\frac{2}{4-d}}. \quad (25)$$

In $d = 2$ we find for $t \gg 1/T$

$$\Gamma(t) \sim \frac{\ln(Tt)Tt}{2\pi\nu_2 D}, \quad (26)$$

so that τ_ϕ satisfies

$$\frac{1}{\tau_\phi} = \frac{\ln(T\tau_\phi)T}{2\pi\nu_2 D}. \quad (27)$$

Keeping in mind that in a good metal $2\pi\nu_2 D \gg 1$, this implies to leading order

$$\frac{1}{\tau_\phi} = \frac{\ln(2\pi\nu_2 D)T}{2\pi\nu_2 D}, \quad (28)$$

in agreement with Ref. [11]. Finally, in $d > 2$ the long-time behavior of $\Gamma(t)$ is dominated by the term proportional to t in the second line of Eq.(19). The total dephasing rate in $d > 2$ can then be written as

$$\begin{aligned}
\frac{1}{\tau_\phi} &= \Gamma_0 + \int \frac{d\mathbf{q}d\omega}{(2\pi)^d} g(\mathbf{q}, \omega) \left[\frac{1}{\pi} \frac{D\mathbf{q}^2}{(D\mathbf{q}^2)^2 + \omega^2} \right] \\
&= \Gamma_0 + \tilde{C}_d T^{\frac{d}{2}} / (\nu_d D^{\frac{d}{2}}),
\end{aligned} \tag{29}$$

where

$$\tilde{C}_d = \frac{2^{2-d}}{\pi^{\frac{d}{2}}(d-2)\Gamma(\frac{d}{2})\sin(\frac{d}{4}\pi)}. \tag{30}$$

Note that for $d \rightarrow 2$ both prefactors C_d and $\tilde{C}_d$ diverge as $\pi^{-1}|d-2|^{-1}$, signalling logarithmic corrections in $d = 2$. The term in the braces of Eq.(29) is the dynamic structure factor of the diffusing electrons in the regime $|\omega| \lesssim T$, where the detailed balance factor $e^{-\omega/T}$ can be replaced by unity. This term agrees with the semiclassical dephasing rate derived by Chakravarty and Schmid [17], see also Ref [18]. It should be kept in mind, however, that Eq.(29) is only valid in $d > 2$, where the integral is finite. Diagrammatically Eq.(29) ignores vertex corrections in the Bethe-Salpeter equation for the Cooperon, which become important in $d \leq 2$. In this case Eq.(29) should be replaced by the more general expressions (18,19), which are free of infrared divergencies.

Our $\Gamma(t)$ corresponds precisely to the function $f_d(t)$ introduced in a recent preprint by Golubev and Zaikin [19]. To make contact with this work, let us *assume* that Eq.(2) remains valid for potentials $V(\mathbf{r}, t)$ due to Nyquist noise with frequencies in the range $|\omega| < 1/\tau_{\text{el}}$, so that in Eqs.(18,19) we may approximate $g(\mathbf{q}, \omega) \approx \Theta(\tau_{\text{el}}^{-1} - |\omega|)\omega \coth(\frac{\omega}{2T})/(\nu_d D\mathbf{q}^2)$. Then we obtain in the quantum regime $Tt \ll 1$ in quasi 1d to leading order $\Gamma(t) \sim \sqrt{2}\pi^{-1}\tau_{\text{el}}^{-1/2}t/(\nu_1 D^{\frac{1}{2}})$, which agrees with the leading term in the expansion of the function $f_1(t)$ given in Eq.(28) of Ref. [19]. Moreover, also the subleading corrections to $f_1(t)$ given by Golubev and Zaikin [19] can be obtained within our eikonal expansion [12]. Hence, at least in $d = 1$ we can completely reproduce the behavior of the function $f_d(t)$ discussed in Ref. [19] *if we assume that the differential equation (2) for the Cooperon remains valid when the classical potential is replaced by a quantum field mediating the Coulomb interaction*. This replacement has been claimed by Golubev and Zaikin to be consistent with a fully quantum mechanical calculation. It is the origin for the discrepancies between their work and Ref.

[11].

IV. DEPHASING DUE TO EXTERNAL FIELDS

In the experiments [7,10] microwaves are coupled into the system via an antenna attached to a suitable waveguide, such that alternating longitudinal currents are induced in the sample. Keeping in mind that the precise way in which the microwaves couple into the system is not known, we assume for simplicity that the electrons feel a longitudinal electric field of the form

$$E(\mathbf{r}, t) = E_0 \cos(\mathbf{q}_0 \cdot \mathbf{r} - \omega_0 t) , \quad (31)$$

where ω_0 is the microwave frequency and the wave-vector $\mathbf{q}_0$ depends on the geometry of the waveguide and the antenna. The corresponding potential in Eq.(2) is

$$V(\mathbf{r}, t) = V_0 \sin(\mathbf{q}_0 \cdot \mathbf{r} - \omega_0 t) , \quad (32)$$

with $E_0 = q_0 V_0 / e$. Let us emphasize that this is the total screened potential, which is the sum of the external potential and the induced potential. Of course, the Maxwell equation inside a metal contains a dissipative term, so that the field inside the metal is not given by a simple propagating wave [20]. In general we expect that the field distribution inside the metal depends on the boundary conditions and on the precise manner in which the microwaves are coupled into the system. Such a calculation is beyond the scope of this work. However, if the spatial variation of the field is sufficiently slow (i.e. q_0 is sufficiently small) the field inside the metal can still be approximated by a plane wave. To estimate the upper limit for q_0 where this approximation is correct, let us assume that the external potential applied to the electrons is $V^{\text{ext}}(\mathbf{r}, t) = V_0^{\text{ext}} \sin(\mathbf{q}_0 \cdot \mathbf{r} - \omega_0 t)$. The total potential is then

$$V(\mathbf{r}, t) = V_0^{\text{ext}} \text{Im} \left[\epsilon^{-1}(\mathbf{q}_0, \omega_0) e^{i(\mathbf{q}_0 \cdot \mathbf{r} - \omega_0 t)} \right] , \quad (33)$$

where the longitudinal electric function in the diffusive regime is given in Eq.(21). Screening can be ignored in the regime where $\epsilon(\mathbf{q}_0, \omega_0)$ can be approximated by unity. From Eq.(21) it is easy to see that in $d = 1$ this is the case when

$$q_0 \ll \sqrt{\frac{\omega_0}{D}}, \quad (34)$$

while in $d = 2$ the external field is effectively not screened if

$$q_0 \ll \frac{\omega_0}{2\pi e^2 \nu_2 D}. \quad (35)$$

Keeping in mind that in a good metal $2\pi e^2 \nu_2 > 1/\ell$, we see that Eqs.(34,35) together with $\omega_0 < 1/\tau_{el}$ are more restrictive than the condition $q_0 < 1/\ell$ which has to be satisfied in order to use the semiclassical Eq.(2). We assume that q_0 is sufficiently small so that the inequalities (34,35) are valid. From Eq.(8) we then obtain

$$\begin{aligned} V_{t_0}(\mathbf{q}, \omega) &= \frac{V_0^{\text{ext}}}{2} (2\pi)^{d+1} [\delta(\omega - \omega_0) - \delta(\omega + \omega_0)] \\ &\times \left[e^{-i\omega_0 t_0} \delta(\mathbf{q} - \mathbf{q}_0) + e^{i\omega_0 t_0} \delta(\mathbf{q} + \mathbf{q}_0) \right]. \end{aligned} \quad (36)$$

This expression is now inserted into the general results given in Eqs.(7) and (11). For F_1 we get

$$\begin{aligned} F_1(\mathbf{k}, \tau; \mathbf{r}, t) &= -i \frac{eE_0}{q_0} \left\{ e^{i(\mathbf{q}_0 \cdot \mathbf{r} - \omega_0 t_0)} \text{Im} \left(\frac{1 - e^{-D(\mathbf{q}_0^2 + 2\mathbf{k} \cdot \mathbf{q}_0)\tau} e^{i\omega_0 \tau}}{D(\mathbf{q}_0^2 + 2\mathbf{k} \cdot \mathbf{q}_0) - i\omega_0} e^{-i\omega_0 t} \right) \right. \\ &\quad \left. + e^{-i(\mathbf{q}_0 \cdot \mathbf{r} - \omega_0 t_0)} \text{Im} \left(\frac{1 - e^{-D(\mathbf{q}_0^2 - 2\mathbf{k} \cdot \mathbf{q}_0)\tau} e^{i\omega_0 \tau}}{D(\mathbf{q}_0^2 - 2\mathbf{k} \cdot \mathbf{q}_0) - i\omega_0} e^{-i\omega_0 t} \right) \right\}. \end{aligned} \quad (37)$$

Performing the analogous calculation for the function F_2 given in Eq.(11) would result in a rather lengthy expression. Since in the following we are only interested in the leading terms of an expansion in powers of q_0 , it is more convenient to first expand F_1 and then use Eq.(10) to obtain F_2 .

If we take the limit $\mathbf{q}_0 \rightarrow 0$ keeping E_0 constant we obtain a spatially constant field, which has been considered in Ref. [6]. In this limit the microwaves do not affect the density of the electrons. For finite q_0 , however, the electric field induces a density modulation with amplitude $\rho_0 = E_0 q_0 / (4\pi)$. We now show that for sufficiently small microwave power P this

leads to a dephasing rate $1/\tau_{AC}$ proportional to $P^{1/2}$, as observed in Ref. [7]. Note that the microwave power P coupled into the sample can be estimated as [5,10]

$$P = \frac{(E_0 L)^2}{2R_{\text{tot}}} \propto E_0^2, \quad (38)$$

where L is the effective sample length including leads, and R_{tot} is the total resistance.

According to Eqs.(1,4) the weak localization correction $\delta\sigma$ is determined by $F(\mathbf{k}, t; \mathbf{r}, t/2)$. In the experiments [7,10] the wavelength of the microwaves is larger than the size of the sample, so that we may expand $F(\mathbf{k}, t; \mathbf{r}, t/2)$ in powers of q_0 . From Eq.(37) we obtain

$$\begin{aligned} F_1(\mathbf{k}, t; \mathbf{r}, t/2) &= 2DeE_0\omega_0^{-2}g_1(\omega_0 t)\{2k_{\parallel}\sin(\omega_0 t_0) \\ &+ q_0\cos(\omega_0 t_0)[i(1 - 2Dk_{\parallel}^2 t) + 2r_{\parallel}k_{\parallel}]\} + O(E_0 q_0^2). \end{aligned} \quad (39)$$

where $k_{\parallel} = \mathbf{k} \cdot \mathbf{q}_0/q_0$, $r_{\parallel} = \mathbf{r} \cdot \mathbf{q}_0/q_0$ and

$$g_1(x) = x \cos\left(\frac{x}{2}\right) - 2 \sin\left(\frac{x}{2}\right). \quad (40)$$

Inserting this result into Eq.(10) yields

$$\begin{aligned} F_2(\mathbf{k}, t; \mathbf{r}, t/2) &= 4D(eE_0)^2\omega_0^{-3}g_2(\omega_0 t)\sin^2(\omega_0 t_0) \\ &+ O(E_0^2 q_0), \end{aligned} \quad (41)$$

with

$$g_2(x) = x + \frac{x}{2}\cos(x) - \frac{3}{2}\sin(x). \quad (42)$$

Note that the second line in Eq.(39) is the leading correction for finite q_0 and small E_0 . It can be shown [12] that in the limit $q_0 \rightarrow 0$ all higher order terms F_n , $n \geq 3$ in our eikonal expansion vanish, so that the exact solution of the eikonal equation (5) is given by $F_{q_0=0} = [F_1 + F_2]_{q_0=0}$. The fact that the Cooperon in a spatially constant field can be calculated exactly is obvious in a gauge where the electric field is represented in terms of a vector potential [6]. It is reassuring to see that our eikonal expansion reproduces the exact solution in a different gauge. Substituting Eqs.(39,41) into Eq.(4) and performing the $\mathbf{k}$ -integration, we obtain for the weak localization correction to the static conductivity

$$\begin{aligned} \delta\sigma = & -\frac{\sigma_0}{\pi\nu_d} \frac{\omega_0^{\frac{d}{2}-1}}{(4\pi D)^{d/2}} \int_{\omega_0\tau_{\text{el}}}^{\infty} \frac{dx}{x^{d/2}} e^{-\alpha g_3(x)-\gamma x} \\ & \times \frac{1}{\pi} \int_0^\pi d\varphi \frac{e^{\alpha g_3(x)\cos(2\varphi)-i\beta g_1(x)\cos\varphi}}{\sqrt{1-2i\beta g_1(x)\cos\varphi}} . \end{aligned} \quad (43)$$

where

$$g_3(x) = x + \sin x - \frac{8}{x} \sin^2\left(\frac{x}{2}\right) , \quad (44)$$

and we have introduced the dimensionless parameters

$$\alpha = \frac{D(eE_0)^2}{\omega_0^3} , \quad (45)$$

$$\beta = \frac{2D|eE_0|q_0}{\omega_0^2} , \quad (46)$$

$$\gamma = \frac{\Gamma_0}{\omega_0} . \quad (47)$$

Note that after the φ -integration the integral in Eq.(43) is real, so that we may replace the integrand by its real part, which is independent of the sign of E_0 . This is the reason why in the definition (46) of β only the absolute value of E_0 appears. Note that β is proportional to the absolute value of the amplitude $\rho_0 = E_0 q_0 / (4\pi)$ of the density wave associated with the longitudinal electric field.

The order of magnitude of the non-equilibrium dephasing rate $1/\tau_{\text{AC}}$ can be estimated as $1/\tau_{\text{AC}} \approx \omega_0/x_c$, where x_c is the effective large- x cutoff for the integration in Eq.(43). For simplicity we now set $\gamma = 0$. Depending on the ratio $\alpha/\beta = |eE_0|/(2\omega_0 q_0) = |V_0|/(2\omega_0)$, we obtain different behaviors for $1/\tau_{\text{AC}}$. In the limit $\alpha/\beta \rightarrow \infty$ we recover the results of Ref. [6]. In this case $1/\tau_{\text{AC}} \propto \omega_0 \alpha$ for $\alpha \ll 1$, and $1/\tau_{\text{AC}} \propto \omega_0 \alpha^{1/5}$ for $\alpha \gg 1$. Note that α is proportional the microwave power $P \propto E_0^2$ absorbed by the system, while β is proportional to $P^{1/2}$. Obviously, for sufficiently small P we always have $\beta \gg \alpha$. Then the cutoff for the x -integration in Eq.(43) is determined by β , and we can set $\alpha = 0$ to determine x_c . The x -integration is effectively cut off where the integrand starts to oscillate. Thus we estimate x_c from the condition $\beta g_1(x_c) \approx 1$. For $\beta \ll 1$ the effective cutoff x_c is large compared with

unity, so that with Eq.(44) we obtain $1/x_c \propto \beta$. This implies

$$\frac{1}{\tau_{AC}} \propto \omega_0 \beta \quad , \quad \text{for } \alpha \ll \beta \ll 1 . \quad (48)$$

On the other hand, for $\beta \gg 1$ the x -integration is cut off at small x and we approximate $g_1(x) \approx -\frac{x^3}{12}$. This yields

$$\frac{1}{\tau_{AC}} \propto \omega_0 \beta^{1/3} \quad , \quad \text{for } \alpha \ll \beta \text{ and } \beta \gg 1 . \quad (49)$$

Hence, for sufficiently small P the dephasing rate $1/\tau_{AC}$ is proportional to $P^{1/2}$. Moreover, in this regime ω_0/τ_{AC} should be independent of ω_0 as long as the dispersion of the longitudinal density wave (i.e. the dependence of q_0 on ω_0) can be neglected. Note that the condition $\beta \gg \alpha \gg \gamma$ where $1/\tau_{AC}$ should exhibit a $P^{1/2}$ -dependence can also be written as

$$Dq_0^2 \gg \frac{\omega_0}{|V_0|} \Gamma_0 \gg \Gamma_0 . \quad (50)$$

Thus, for finite Γ_0 the value of q_0 must be sufficiently large to observe the $P^{1/2}$ -law. Keeping in mind that according to the conventional point of view [4–6] the intrinsic dephasing rate Γ_0 should vanish for $T \rightarrow 0$, we conclude that at sufficiently low temperatures and small V_0 Eq.(50) can be satisfied for experimentally relevant wave-vectors q_0 . Note that according to Ref. [5] the observed saturation of the dephasing time, which is typically of the order of a few nanoseconds, is due to some external noise. If this is correct, then the experimentally observed saturation value of the dephasing rate should not be identified with Γ_0 . The same arguments apply for the condition $|V_0| \gg \Gamma_0$ that follows from Eq.(50) together with Eqs.(34,35). For low enough temperatures this inequality should always be satisfied. (Most recent experimental data [22] indicates $\Gamma_0 \rightarrow 0$ for $T \rightarrow 0$ in narrow Ag wires. These probes therefore seem to be suiting to test our findings.) In conclusion, in the limit $T \rightarrow 0$, the only relevant restriction following from Eq.(50) should be $|V_0| \ll \omega_0$.

For convenience, let us summarize the assumptions made in our derivation of the dephasing time due to external microwave radiation in this section. First of all, we have assumed that the microwave field inside the metal can be approximated by a propagating wave with

wave-vector $\mathbf{q}_0$, frequency ω_0 and amplitude $E_0 = q_0 V_0 / e$. We have argued that this approximation is valid in a regime where the dielectric function of the bulk system can be approximated by unity, which is possible if $q_0 \ll \sqrt{\omega_0 / D}$ in $d = 1$, and $q_0 \ll \omega_0 / (2\pi e^2 \nu_2 D)$ in $d = 2$. Throughout this work we have assumed diffusive dynamics and calculated the weak localization correction to the conductivity from the semiclassical equation (2), which is of course only correct for sufficiently small wave-vectors ($q_0 < 1/\ell$) and frequencies ($\omega_0 < 1/\tau_{el}$). Note that the latter inequality sets the upper limit for the microwave frequency where our approach remains valid. If these restrictions are satisfied, then the dephasing rate due to microwaves is

$$\frac{1}{\tau_{AC}} \propto \begin{cases} \omega_0^{2/5} P^{1/5} & \text{for } |V_0| \gg \omega_0 \text{ and } D(eE_0)^2 \gg \omega_0^2, \\ \omega_0^{-2} P & \text{for } |V_0| \gg \omega_0 \text{ and } D(eE_0)^2 \ll \omega_0^2, \\ (q_0 \omega_0)^{1/3} P^{1/6} & \text{for } |V_0| \ll \omega_0 \text{ and } D|eE_0|q_0 \gg \omega_0^2, \\ q_0 \omega_0^{-1} \sqrt{P} & \text{for } |V_0| \ll \omega_0 \text{ and } D|eE_0|q_0 \ll \omega_0^2, \end{cases} \quad (51)$$

where $P \propto E_0^2$ is the microwave-power absorbed by the system, and $V_0 = eE_0/q_0$.

V. COMPARISON WITH EXPERIMENTS AND SUMMARY

Some time ago Wang and Lindelof [7] have measured $1/\tau_{AC}$ as a function of P in magnesium films. Their data from Ref.[7(a)] are reproduced in Fig.1. At $\omega_0/2\pi = 0.66\text{GHz}$ our prediction $\omega_0/\tau_{AC} \propto P^{1/2}$ is in good agreement with the experiment. Although the data at $\omega_0/2\pi = 3.61\text{GHz}$ cannot be fitted by a straight line through the origin, the data roughly scale as $1/\tau_{AC} \propto \omega_0^{-1}$ for fixed and small P . One should keep in mind, however, that in the experiments [7] the precise value of the microwave power coupled into the system was not measured, and the power axis for the two sets of data was rescaled differently. Further evidence for the $P^{1/2}$ -law can be found in Fig.19 of Ref.[7(b)].

Recent measurements of $1/\tau_{AC}$ by Webb *et al.* [10] suggest a $P^{1/5}$ -law for large P in a limited range of frequencies. Our calculation shows that the $P^{1/5}$ -law should hold as long as $\alpha \gg \max\{\beta, 1\}$, while for $\beta \gg \max\{\alpha, 1\}$ we predict $1/\tau_{AC} \propto \beta^{1/3} \propto P^{1/6}$. Keeping in

mind that $\alpha/\beta \propto \omega_0^{-1}$ we predict a crossover from a $P^{1/5}$ - via a $P^{1/6}$ - to a $P^{1/2}$ -behavior as the frequency is increased. The data shown in Fig.6 of Ref. [10] are consistent with the existence of such a crossover.

In summary, by means of an eikonal expansion for the Cooperon in a slowly varying scalar potential we have derived a general expression for the dephasing rate due to fluctuating electric fields in disordered metals. Our method is a physically transparent alternative to the path-integral approach used in Ref. [11]. For randomly fluctuating fields with zero average and arbitrary covariance the dephasing rate can be obtained from Eqs.(18,19). These expressions take vertex corrections into account and remain finite in reduced dimensions, where the well-known [17,18] semiclassical result Eq.(29) is infrared divergent for some physically relevant $g(\mathbf{q}, \omega)$. For example, in the case of $1/f$ -noise [18], where $g(\mathbf{q}, \omega) \propto 1/\omega$, the integral in Eq.(29) is divergent in $d \leq 2$, while our more general result (18,19) is finite. We have also studied dephasing due to external electric fields, and have proposed an explanation for the data of Ref. [7]. Finally, we point out that our eikonal method can also be used to calculate the Diffuson in a fluctuating electric field, which is of current interest in several contexts [21].

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FIGURES

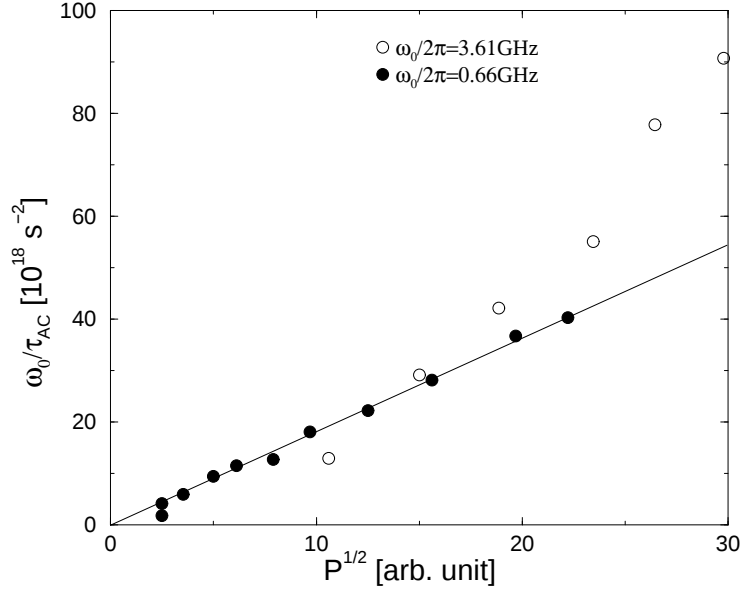


FIG. 1. Data for ω_0/τ_{AC} as function of $P^{1/2}$ from Fig.3 of Ref.[7(a)]. Here P is the microwave power coupled into the system. The solid line is a fit of the data at $\omega_0/2\pi = 0.66\text{GHz}$ to our prediction $\omega_0/\tau_{AC} \propto P^{1/2}$, which is valid for small P .